

Above ω_R no external negative resistance is exhibited by a tunnel diode by definition—in this case all $j\omega$ plots terminate somewhere in the RH H plane. It is therefore justified to draw an arbitrary loop from just above ω_R to just below $-\omega_R$ in the RH H plane (along a constant resistance or conductance line just to the right of the imaginary-axis, say) regardless of which limiting case of Table I applies.

Analogous limiting cases will now be found for the ρ' plane, for $R' = Z_C(p)|_{p \rightarrow \infty}$.

$$\text{If } Z_L(p)|_{p \rightarrow \infty} \rightarrow \frac{1}{pC},$$

$$\rho'(p)|_{p \rightarrow \infty} \rightarrow -1. \quad (10)$$

If $Z_L(p)|_{p \rightarrow \infty} \rightarrow R$,

$$\rho'(p)|_{p \rightarrow \infty} \rightarrow \frac{R + R'}{R - R'}. \quad (11)$$

If $Z_L(p)|_{p \rightarrow \infty} \rightarrow pL$,

$$\rho'(p)|_{p \rightarrow \infty} \rightarrow +1. \quad (12)$$

The infinite CCW semicircle in the LH p plane of Fig. 2(a) will, therefore, coalesce into a single point on the real ρ or ρ' axis, according to Table II.

The question of where an arbitrary loop can be drawn without ambiguity presents some difficulty. It is important to distinguish between whether the Smith chart is being used with the stability criterion in terms of admittance or in terms of voltage reflection coefficient. Figure 3 illustrates the difficulty with the aid of Tables I and II, with Z_L representing the tunnel-diode equivalent circuit either in the form of Fig. 3(a) or (b), and with $Z_C(p)$ equal to a constant. Note that the H -plane criterion is associated with a closing loop through the region of the origin. The closing loops for the ρ' -plane criterion, however, pass through $\rho = \pm 1$ according to whether L or C , respectively, predominates as $p \rightarrow \infty$.

To summarize:

- 1) The numerator of $\rho(p)$ may have zeros in the RH p plane other than "active" ones which would have to be determined.
- 2) The arbitrary closing loop in the ρ' plane cannot be so easily dismissed (see Fig. 4) as in the H -plane.
- 3) No further information on *stability* is forthcoming by considering ρ' rather than H .

It is advisable, therefore, that when using the Smith chart for predicting simultaneously the stability and gain of reflection amplifiers, for example, the stability criterion itself should be formulated in terms of H to avoid ambiguity. The Smith chart plot is visualized as a distorted H -plane plot for this purpose.

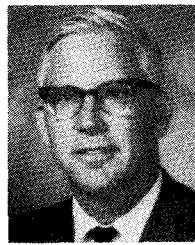
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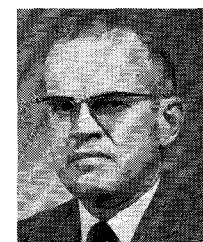


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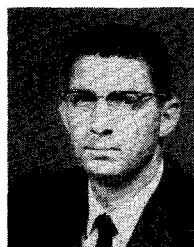


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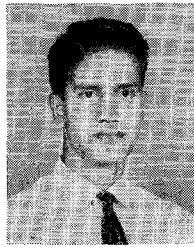
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